

# SMD Schottky Barrier Rectifier

**COMCHIP**  
SMD DIODE SPECIALIST

## SS32-G THRU SS310-G

**Forward Current: 3.0 Amp**

**Reverse Voltage: 20 ~ 100 Volts**

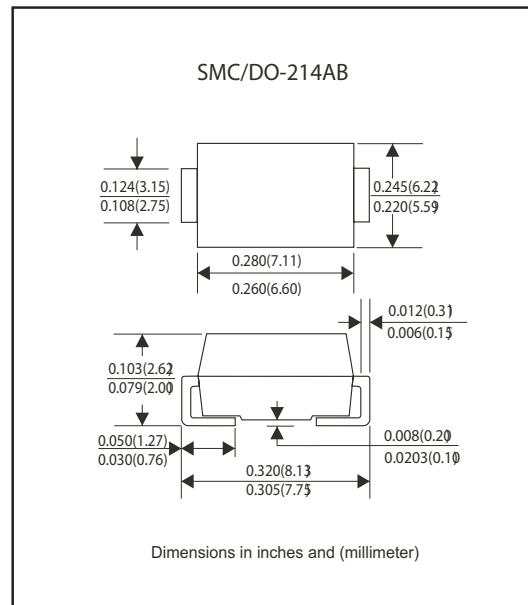


### Features

- Ideal for surface mount applications
- Easy pick and place
- Plastic packages has Underwriters lab. Flammability classification 94V-0
- Built-in strain relief
- Low forward voltage drop

### Mechanical Data

- Case: JEDEC DO-214AB molded plastic
- Epoxy: UL 94-0 rate flame retardant
- Terminal: Solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Mounting position: Any
- Approx. Weight: 0.21 gram



### Maximum Rating and Electrical Characteristics

Parameter	Symbol	SS32-G	SS34-G	SS36-G	SS310-G	Unit
Max. Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	20	40	60	100	V
Max. DC Blocking Voltage	V <sub>DC</sub>	20	40	60	100	V
Max. RMS Voltage	V <sub>RMS</sub>	14	28	42	70	V
Peak Surge Forward Current 8.3ms single halfsine-wave superimposed on rateload ( JEDEC method )	I <sub>FSM</sub>			80		A
Max. Average Forward Current	I <sub>o</sub>			3.0		A
Max. Instantaneous Forward Current at 2.0 A	V <sub>F</sub>		0.50	0.75	0.85	V
Max. DC Reverse Current at Rated DC Blocking Voltage      Ta=25°C	I <sub>R</sub>			0.5		mA
				20	10	
Max. Thermal Resistance (Note 1)	R <sub>θJA</sub> R <sub>θJL</sub>		50 10			°C/W
Operating Junction temperature	T <sub>j</sub>		-50 to +125			°C
Storage Temperature	T <sub>STG</sub>		-65 to +150			°C

**"-G" suffix designates RoHS compliant Version**

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## Rating and Characteristic Curves (SS32-G Thru SS310-G)

Fig. 1 - Reverse Characteristics

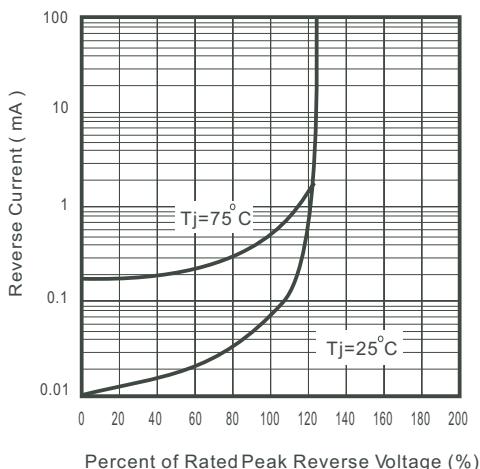


Fig.2 - Forward Characteristics

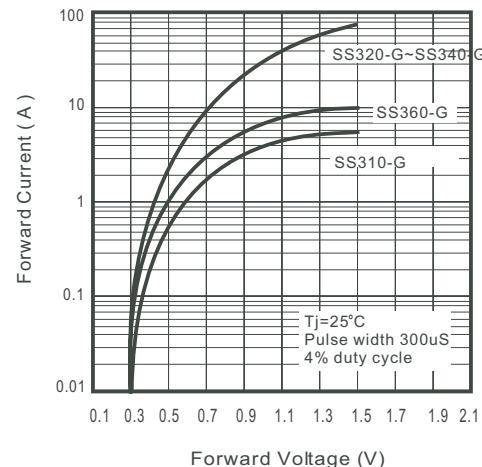


Fig. 3 - Junction Capacitance

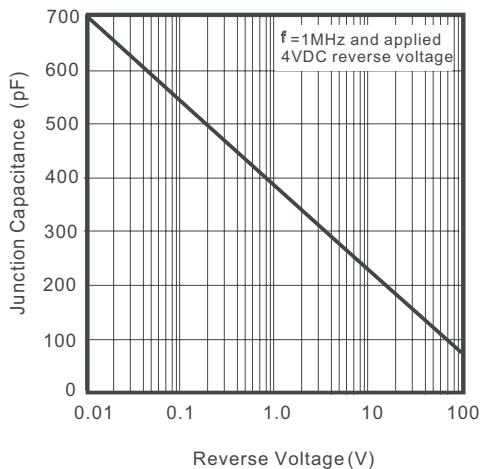


Fig. 4 - Current Derating Curve

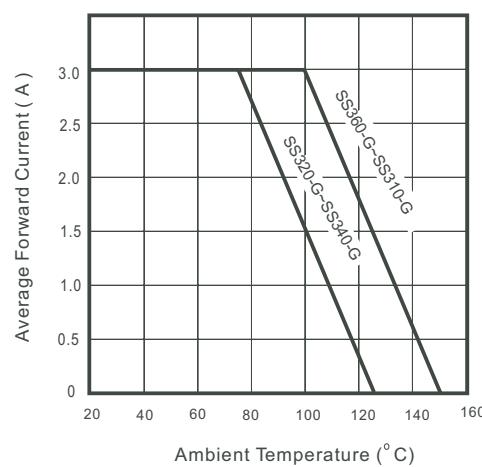


Fig. 5 - Non Repetitive Forward Surge Current

